

# SANYO Semiconductors DATA SHEET

# TND308TD

ExPD (Excellent Power Device)

# General Purpose Driver for PDP Sustain Pulse Drive, Motor Drive, Switching Power Supply, and DC / DC Converter Applications

#### **Features**

- · Dual buffer.
- · Monolithic structure(High voltage CMOS process adopted).
- Withstand voltage of 25V is assured.
- Wide range of operating voltage: 4.5V to 25V.
- · Peak output current: 1A.
- Fast switching time(30ns typical at 1000pF load).
- Fully compatible input to TTL/CMOS (VIH=not more than 2.6V, at VDD=4.5 to 25V).

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	VDD		0 to 25	V
Input Voltage	VIN		GND-0.3 to V <sub>DD</sub> +0.3	V
Allowable Power Dissipation	P <sub>D</sub> max		0.25	W
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Operating Supply Voltage	VDD		4.5 to 25	V
Operating Temperature	Topr		-40 to +125	°C

#### Electrical Characteristics (AC Characteristics) at Ta=25°C, V<sub>DD</sub>=18V, V<sub>IN</sub>=5V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Turn-On Rise Time	tr	C <sub>L</sub> =1000pF		30	45	ns
Turn-Off Fall Time	tf	C <sub>L</sub> =1000pF		30	45	ns
Delay Time	t <sub>D</sub> 1	CL=1000pF		30	45	ns
	t <sub>D</sub> 2	C <sub>L</sub> =1000pF		45	60	ns

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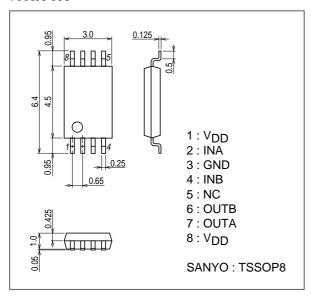
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### **Electrical Characteristics** (DC Characteristics) at Ta=25°C, V<sub>DD</sub>=4.5 to 25V

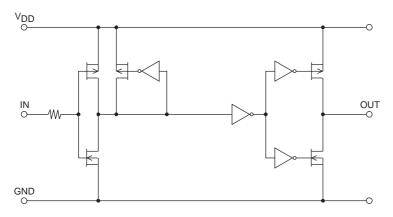
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Logic "1" Input Voltage	VIH		2.6			V
Logic "0" Input Voltage	VIL				0.8	V
Input Bias Current	IIN	VIN=0 or VDD	-1		1	μΑ
High Level Output Voltage	VOH	IO=0	V <sub>DD</sub> -0.1			V
Low Level Output Voltage	VOL	IO=0			0.1	V
V <sub>DD</sub> Supply Current	Isupp	V <sub>DD</sub> =10V, V <sub>IN</sub> =3V, (both inputs)		1.0	4.5	mA
		V <sub>DD</sub> =10V, V <sub>IN</sub> =0, (both inputs)			0.2	mA
Output High Short Circuit Pulse Current	IO+	V <sub>DD</sub> =18V, PW≤10μs, V <sub>OUT</sub> =0		1.0		Α
Output Low Short Circuit Pulse Current	10-	V <sub>DD</sub> =18V, PW≤10μs, V <sub>OUT</sub> =18V		1.0		Α
Output On Resistance	ROUT	V <sub>DD</sub> =18V, Iload=10mA, V <sub>OUT</sub> ="H"		8	12	Ω
		V <sub>DD</sub> =18V, Iload=10mA, V <sub>OUT</sub> ="L"		6	10	Ω

### **Package Dimensions**

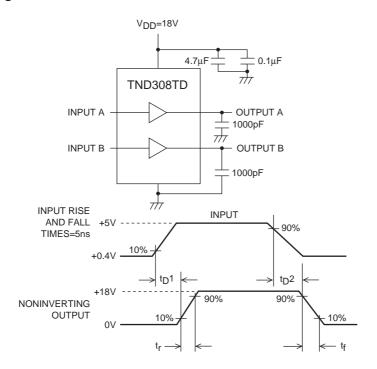
unit : mm 7006A-006

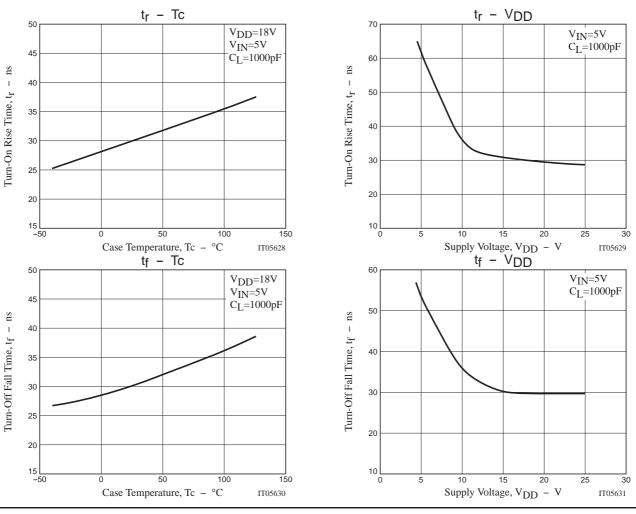


# **Block Diagram**

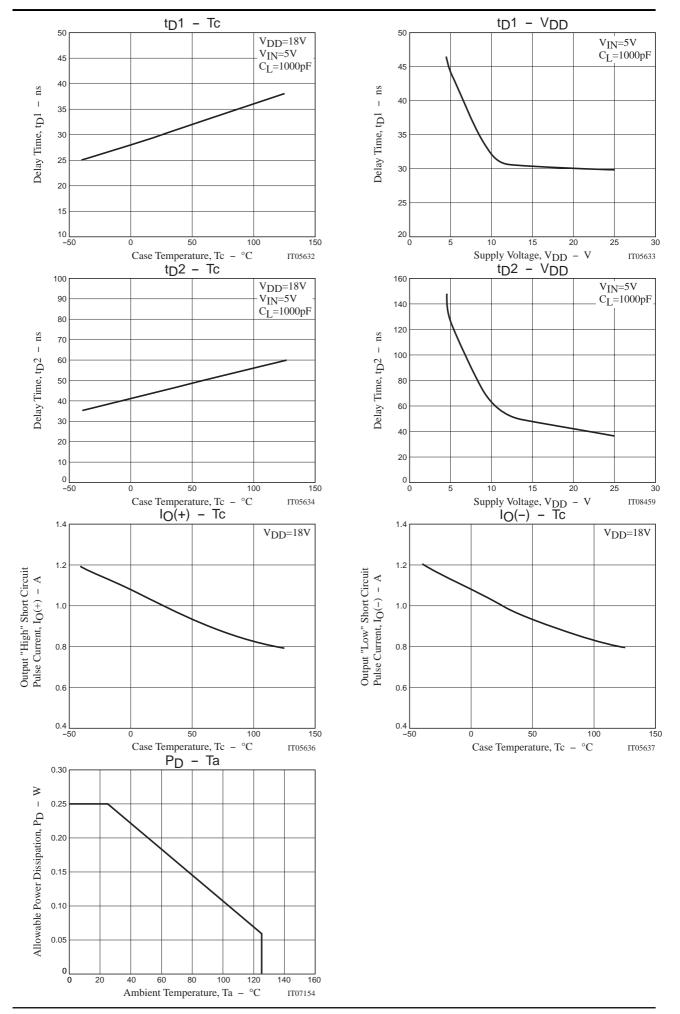


#### **Switching Time Test Circuit**





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